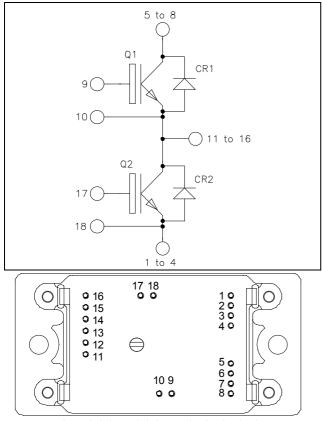


Phase leg Trench + Field Stop IGBT3 Power Module



Pins 1/2/3/4 ; 5/6/7/8 ; 11/12/13/14/15/16 must be shorted together

$V_{CES} = 600V$ $I_{C} = 200A$ @ Tc = 80°C

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Fast Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant

All ratings (a) $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V _{CES}	Collector - Emitter Breakdown Voltage		600	V
I _C	Continuous Collector Current	$T_C = 25^{\circ}C$	290	
	Continuous Conector Current	$T_C = 80^{\circ}C$	200	А
I _{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	400	
V_{GE}	Gate – Emitter Voltage		± 20	V
PD	Maximum Power Dissipation	$T_C = 25^{\circ}C$	625	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	400A @ 550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com APTGT200A602G - Rev 1 October 2012



Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				50	μA
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.5	1.9	V
		$I_{\rm C} = 200 {\rm A}$ $T_{\rm j} =$	$T_{j} = 150^{\circ}C$		1.7		v
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 2 \text{ mA}$		5.0	5.8	6.5	V
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			12.3		
Coes	Output Capacitance	$V_{CE} = 25V$			0.8		nF
C _{res}	Reverse Transfer Capacitance	f = 1 MHz			0.4		
Q _G	Gate charge	$V_{GE}=\pm 15V, I_{C}=200A$ $V_{CE}=300V$			2.1		μC
T _{d(on)}	Turn-on Delay Time	Inductive Switching	(25°C)		115		
T _r	Rise Time	$V_{GE} = \pm 15V$			45		ns
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 200A$			225		
$T_{\rm f}$	Fall Time	$R_G = 2\Omega$			55		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_C = 200A$ $R_G = 2\Omega$			130		ns
Tr	Rise Time				50		
T _{d(off)}	Turn-off Delay Time				300		
T _f	Fall Time				70		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $T_j =$	= 25°C		1		mJ
Lon	Turn on Energy	$V_{Bus} = 300V$ $T_j =$	= 150°C		1.8		1115
E _{off}	Turn off Energy		= 25°C		5.7		mJ
Loff		$R_G = 2\Omega$ $T_j = 150^{\circ}C$			7		1115
I _{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 360V$ $t_p \le 6\mu s$; $T_i = 150^{\circ}C$			1000		А
R _{thJC}	Junction to Case Thermal Resistance					0.24	°C/W

Reverse diode ratings and characteristics

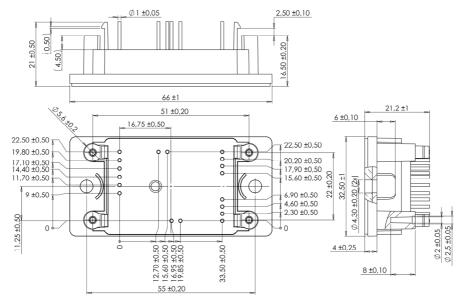
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I _{RM}	Maximum Reverse Leakage Current	V _R =600V				50	μΑ
I _F	DC Forward Current		$Tc = 80^{\circ}C$		200		Α
$V_{\rm F}$	Diode Forward Voltage	$I_{\rm F} = 200 {\rm A}$	$T_i = 25^{\circ}C$		1.6	2	v
v F		$V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.5		
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		130		- ns
		$I_{\rm F} = 200 \text{A}$ $V_{\rm R} = 300 \text{V}$ $T_{\rm j} =$	$T_{j} = 150^{\circ}C$		225		
Q _{rr} Reverse Recovery	Daviance Bacavany Change		$T_j = 25^{\circ}C$		9		
	Reverse Recovery Charge		$T_{j} = 150^{\circ}C$		19	μ	μC
Er	Reverse Recovery Energy		$T_j = 25^{\circ}C$		2.3		mJ
			$T_{j} = 150^{\circ}C$		4.7		
R _{thJC}	Junction to Case Thermal Resistance					0.4	°C/W



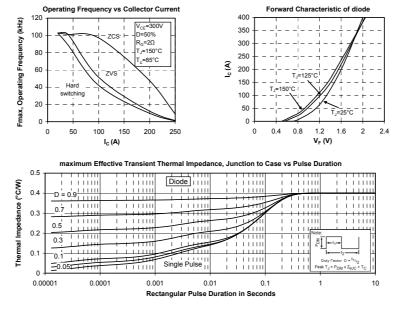
Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T _J	Operating junction temperature range			-40		175	
T _{STG}	Storage Temperature Range			-40		125	°C
T _C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					75	g

SP2 Package outline (dimensions in mm)

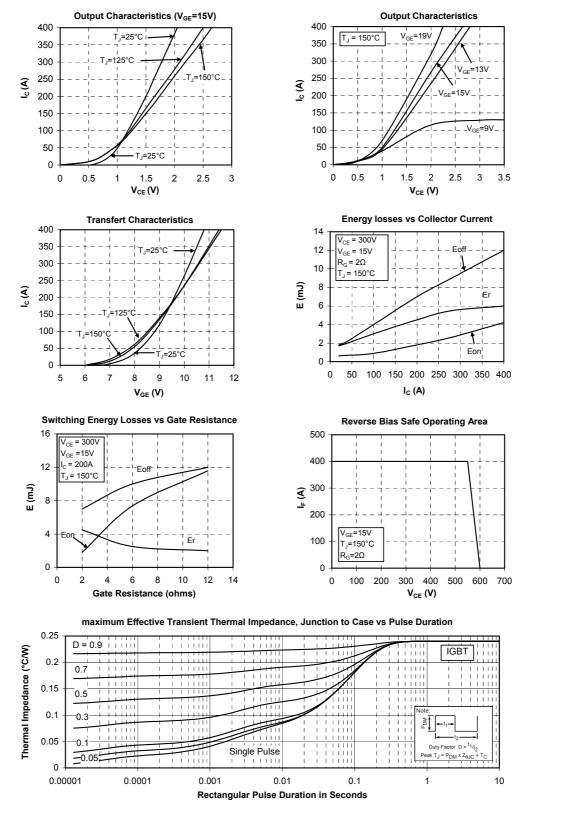


Typical Performance Curve



APTGT200A602G-Rev 1 October 2012





APTGT200A602G - Rev 1 October 2012



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